



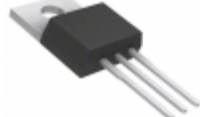




	<h2>HGTP3N60A4</h2>
	<p>Hersteller-Teilenummer: HGTP3N60A4</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: IGBT 600V 17A 70W TO220AB</p> <p>Datenblätter: 1.HGTP3N60A4.pdf 2.HGTP3N60A4.pdf</p> <p>RoHS Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1897 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	HGTP3N60A4
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	IGBT 600V 17A 70W TO220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-IGBTs-
Teilstatus	1897 pcs Stock
detaillierte Beschreibung	IGBT 600V 17A 70W Through Hole TO-220AB
Serie	-
Eingabetyp	Standard
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Leistung - max	70W
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Strom - Kollektor (Ic) (max)	17A
Spannung - Kollektor-Emitter-Durchbruch (max)	600V
IGBT-Typ	-
VCE (on) (Max) @ Vge, Ic	2.7V @ 15V, 3A
Strom - Collector Pulsed (Icm)	40A
Schaltenergie	37µJ (on), 25µJ (off)
Gate-Ladung	21nC
Td (ein / aus) bei 25 ° C	6ns/73ns
Testbedingung	390V, 3A, 50 Ohm, 15V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	HGTP3N60A4_NL

HGTP3N60A4 ist neu im Original, Suche HGTP3N60A4 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie HGTP3N60A4 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage HGTP3N60A4: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>HGTP2N120CN AMI Semiconductor / ON Semiconductor IGBT 1200V 13A 104W TO220AB</p>	 <p>HGTP3N60A4G3N60A4 FSC FSC TO220</p>	 <p>HGTP3N60A4D AMI Semiconductor / ON Semiconductor IGBT 600V 17A 70W TO220AB</p>	 <p>HGTP3N60A4 Fairchild/ON Semiconductor IGBT 600V 17A 70W TO220AB</p>
 <p>HGTP2N120BN FAIRCHILD HGTP2N120BN FAIRCHILD</p>	 <p>HGTP2N120CND Intersil HGTP2N120CND Intersil</p>	 <p>HGTP2N120BND Intersil HGTP2N120BND Intersil</p>	 <p>HGTP3N60A4_0846+ FAIRCHI FAIRCHI TO-220</p>

heiße Teile

Mehr

⊗ HGTP10N120BN	↔ HGTP10N40C1	⇒ HGTP10N40E1D	D HGTP10N40F1D	⇒ HGTP10N50C1
⊣ HGTP11N120CN	⊗ HGTP11N120CND	D HGTP12N60A4	⇒ HGTP12N60A4	⇒ HGTP12N60A4D
⊗ HGTP12N60A4D	⊣ HGTP12N60B3	⊗ HGTP12N60B3D	↔ HGTP12N60C3	⇒ HGTP12N60C3
D HGTP14N36G3VL	⊗ HGTP14N40F3VL	⊣ HGTP14N41G3	⊗ HGTP15N120C3	⇒ HGTP15N40C1
⇒ HGTP15N50E1	↔ HGTP1N120BND	⊗ HGTP1N120CND	⊣ HGTP20N35G3VL	⇒ HGTP20N36G3VL
↔ HGTP20N60A4	⇒ HGTP20N60A4	D HGTP20N60B3	⊗ HGTP20N60B3D	⊣ HGTP20N60C3
⊗ HGTP20N60C3D	D HGTP2N120BN	⇒ HGTP2N120BND	↔ HGTP2N120CN	⇒ HGTP2N120CN
⊣ HGTP2N120CND	⊗ HGTP3N60A4	↔ HGTP5N120BND	⇒ HGTP5N120BND	⇒ HGTP7N60A4
⊗ HGTP7N60A4	⊣ HGTP7N60A4D	⊗ HGTP7N60A4D	D HGTP7N60B3	⇒ HGTP7N60B3D
↔ HGTP7N60B3D	⊗ HGTP7N60C3	⊣ HGTP7N60C3D	⊗ HGTP7N60C3D	⇒ HGTP7NA60A4D

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